

## Features

- Advanced Shield Gate Trench technology
- Super Low Gate Charge
- High-Speed Switching
- 100% EAS Guaranteed
- Green Device Available

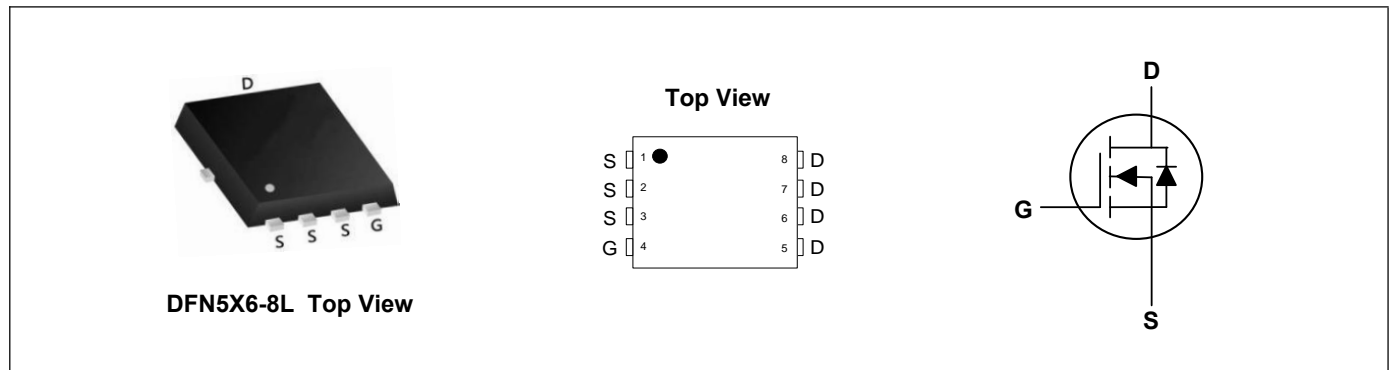
## Applications

- High Frequency Point-of-Load, Synchronous Buck Converter
- Networking DC-DC Power System
- Load Switch

## Product Summary



$V_{DS}$	80	V
$I_D$	165	A
$R_{DS(ON)}$ (at $V_{GS}=10V$ )	2.2	m $\Omega$



## Absolute Maximum Ratings ( $T_c=25^\circ\text{C}$ , unless otherwise noted)

Parameter	Symbol	Rating	Units
Drain-Source Voltage	$V_{DS}$	80	V
Gate-Source Voltage	$V_{GS}$	$\pm 20$	V
Continuous Drain Current <sup>1</sup>	$I_D$	165	A
Pulsed Drain Current <sup>2</sup>	$I_{DM}$	660	A
Single Pulse Avalanche Energy <sup>3</sup>	$E_{AS}$	841	mJ
Total Power Dissipation <sup>4</sup>	$P_D$	167	W
Storage Temperature Range	$T_{STG}$	-55 to 175	$^\circ\text{C}$
Operating Junction Temperature Range	$T_J$	-55 to 175	$^\circ\text{C}$

## Thermal Characteristics

Parameter	Symbol	Typ	Max	Unit
Thermal Resistance Junction-Ambient <sup>1</sup>	$R_{\theta JA}$	---	50	$^\circ\text{C}/\text{W}$
Thermal Resistance Junction-Case <sup>1</sup>	$R_{\theta JC}$	---	0.9	$^\circ\text{C}/\text{W}$

**Electrical Characteristics (T<sub>J</sub>=25°C, unless otherwise noted)**

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	V <sub>GS</sub> =0V, I <sub>D</sub> =250uA	80	---	---	V
Static Drain-Source On-Resistance	R <sub>DS(ON)</sub>	V <sub>GS</sub> =10V, I <sub>D</sub> =15A	---	1.7	2.2	mΩ
Gate Threshold Voltage	V <sub>GS(th)</sub>	V <sub>GS</sub> =V <sub>DS</sub> , I <sub>D</sub> =250uA	2	---	4	V
Drain-Source Leakage Current	I <sub>DSS</sub>	V <sub>DS</sub> =80V, V <sub>GS</sub> =0V	---	---	1	uA
Gate-Source Leakage Current	I <sub>GSS</sub>	V <sub>GS</sub> =±20V, V <sub>DS</sub> =0V	---	---	±100	nA
Forward Transconductance	g <sub>fs</sub>	V <sub>DS</sub> =5V, I <sub>D</sub> =15A	---	206	---	S
Total Gate Charge	Q <sub>g</sub>	V <sub>DS</sub> =40V, V <sub>GS</sub> =10V, I <sub>D</sub> =20A	---	116	---	nC
Gate-Source Charge	Q <sub>gs</sub>		---	24	---	
Gate-Drain Charge	Q <sub>gd</sub>		---	16	---	
Turn-On Delay Time	T <sub>d(on)</sub>	V <sub>DS</sub> =40V, V <sub>GS</sub> =10V, R <sub>G</sub> =1Ω, I <sub>D</sub> =20A	---	22	---	ns
Rise Time	T <sub>r</sub>		---	35	---	
Turn-Off Delay Time	T <sub>d(off)</sub>		---	52	---	
Fall Time	T <sub>f</sub>		---	19	---	
Input Capacitance	C <sub>iss</sub>	V <sub>DS</sub> =40V, V <sub>GS</sub> =0V, f=1MHz	---	5860	---	pF
Output Capacitance	C <sub>oss</sub>		---	776	---	
Reverse Transfer Capacitance	C <sub>rss</sub>		---	19	---	

**Drain-Source Diode Characteristics**

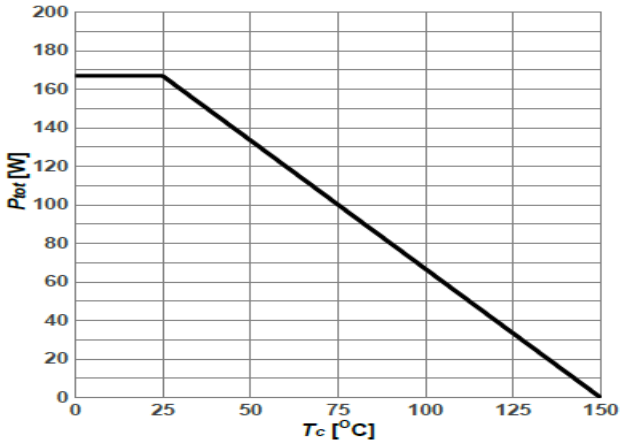
Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Diode Forward Voltage <sup>2</sup>	V <sub>SD</sub>	V <sub>GS</sub> =0V, I <sub>S</sub> =20A, T <sub>J</sub> =25°C	---	---	0.8	V
Reverse Recovery Time	t <sub>rr</sub>	I <sub>F</sub> =20A	---	49.5	---	nS
Reverse Recovery Charge	Q <sub>rr</sub>	di/dt=100A/μs, T <sub>J</sub> =25°C	---	99	---	nC

**Note:**

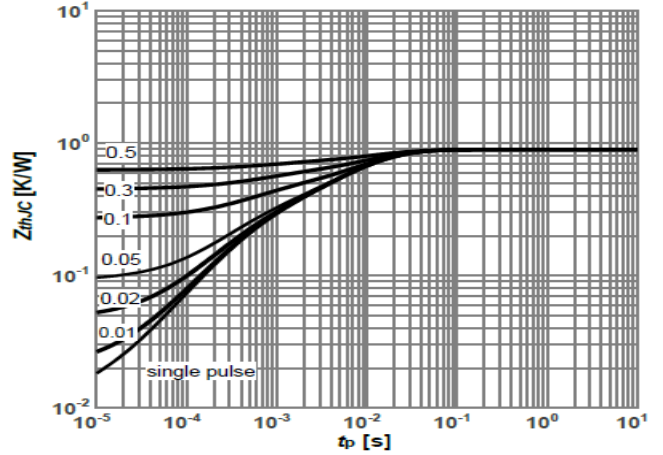
- 1.The data tested by surface mounted on a 1 inch<sup>2</sup> FR-4 board with 2OZ copper.
- 2.The data tested by pulsed, pulse width ≤ 300us, duty cycle ≤ 2%
- 3.The EAS data shows Max. rating. The test condition is V<sub>DD</sub>=50V, R<sub>G</sub>=25Ω, L=0.5mH

**Typical Characteristics**

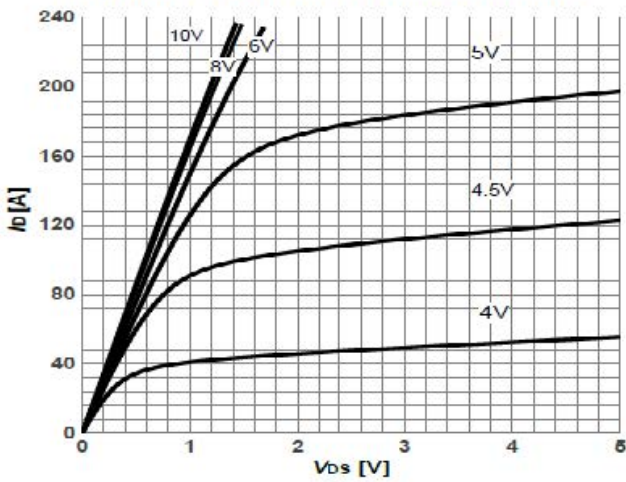
**Diagram 1: Power dissipation**



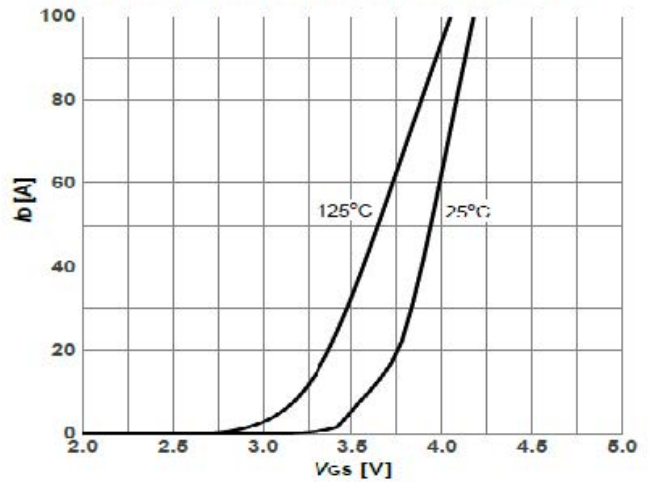
**Diagram 2: Max. transient thermal impedance**



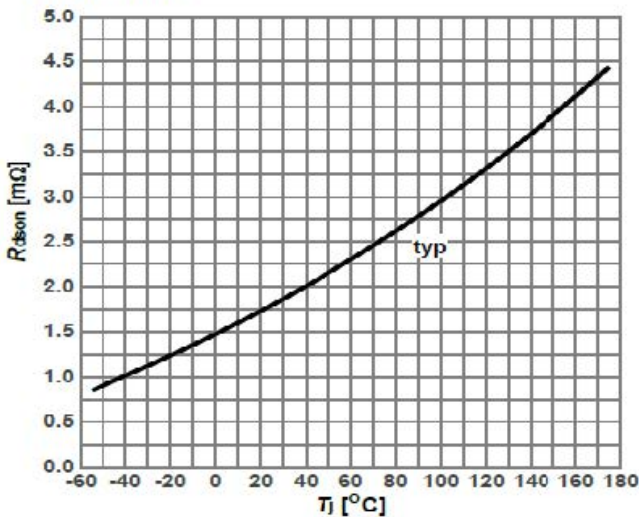
**Diagram 3: Typ. output characteristics**



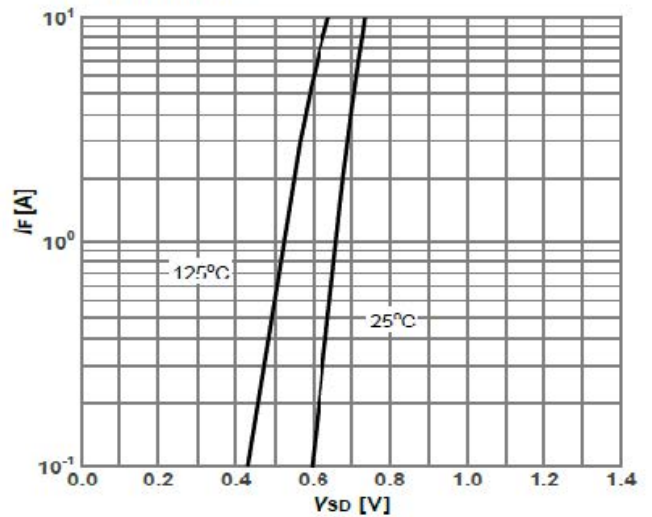
**Diagram 4: Typ. transfer characteristics**



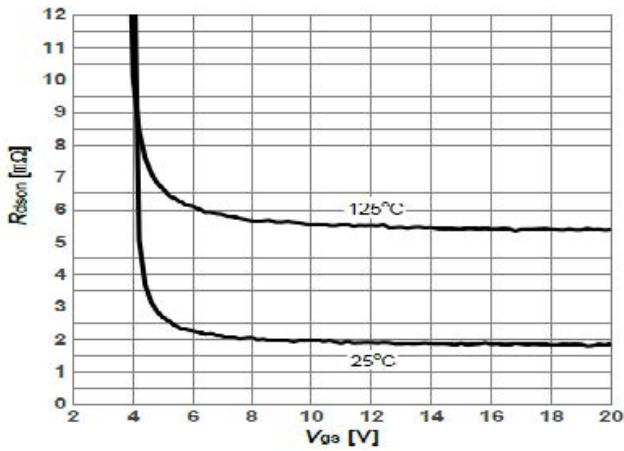
**Diagram 5: On-state resistance vs. Junction temperature**



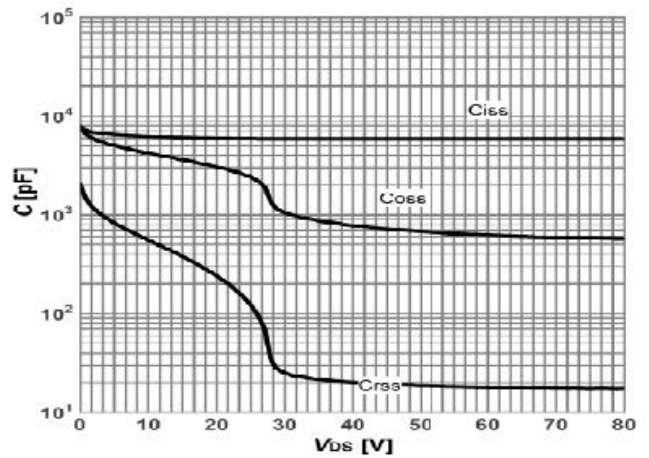
**Diagram 6: Forward characteristics of reverse diode**



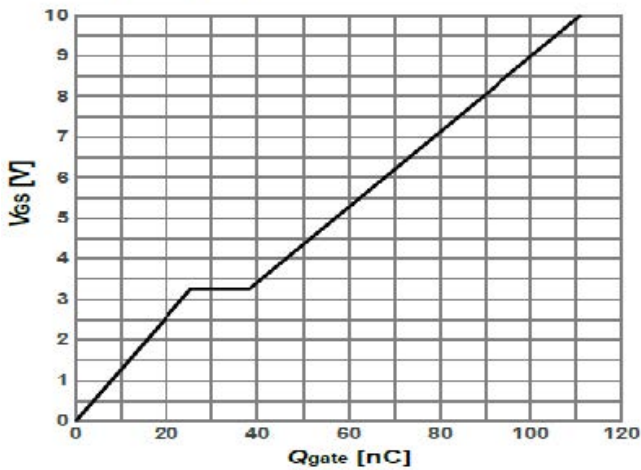
**Diagram 7 : On-state resistance vs. Vgs characteristics**



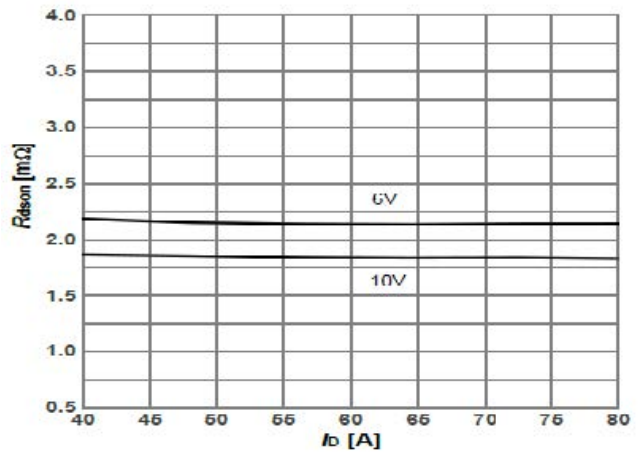
**Diagram 8 : Typ. capacitances**



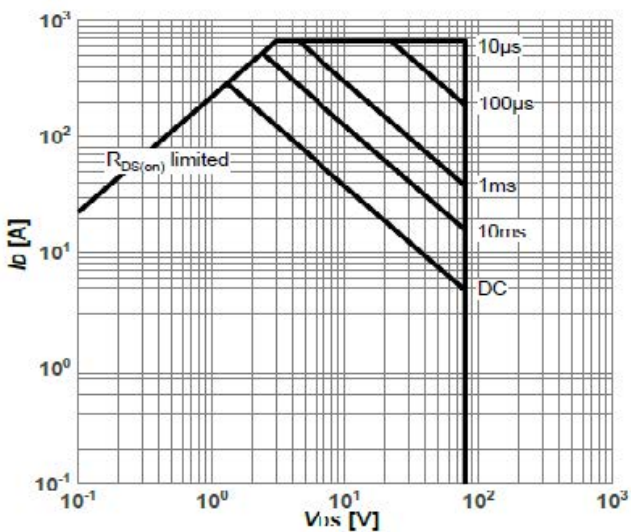
**Diagram 9 : Typ. gate charge**



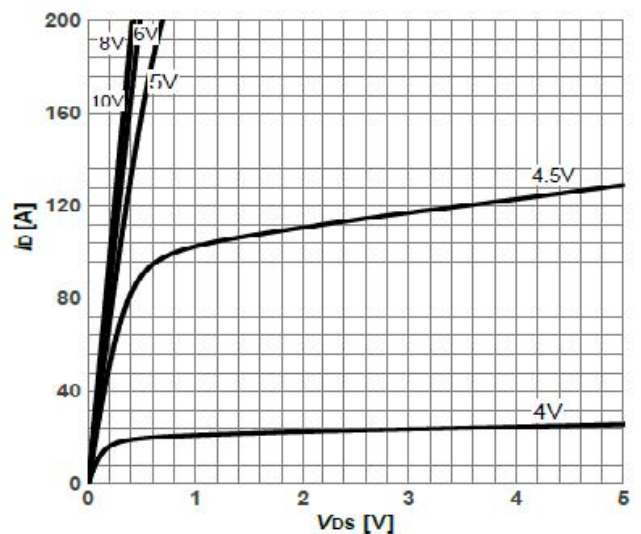
**Diagram10: On-state resistance vs. Drain current**



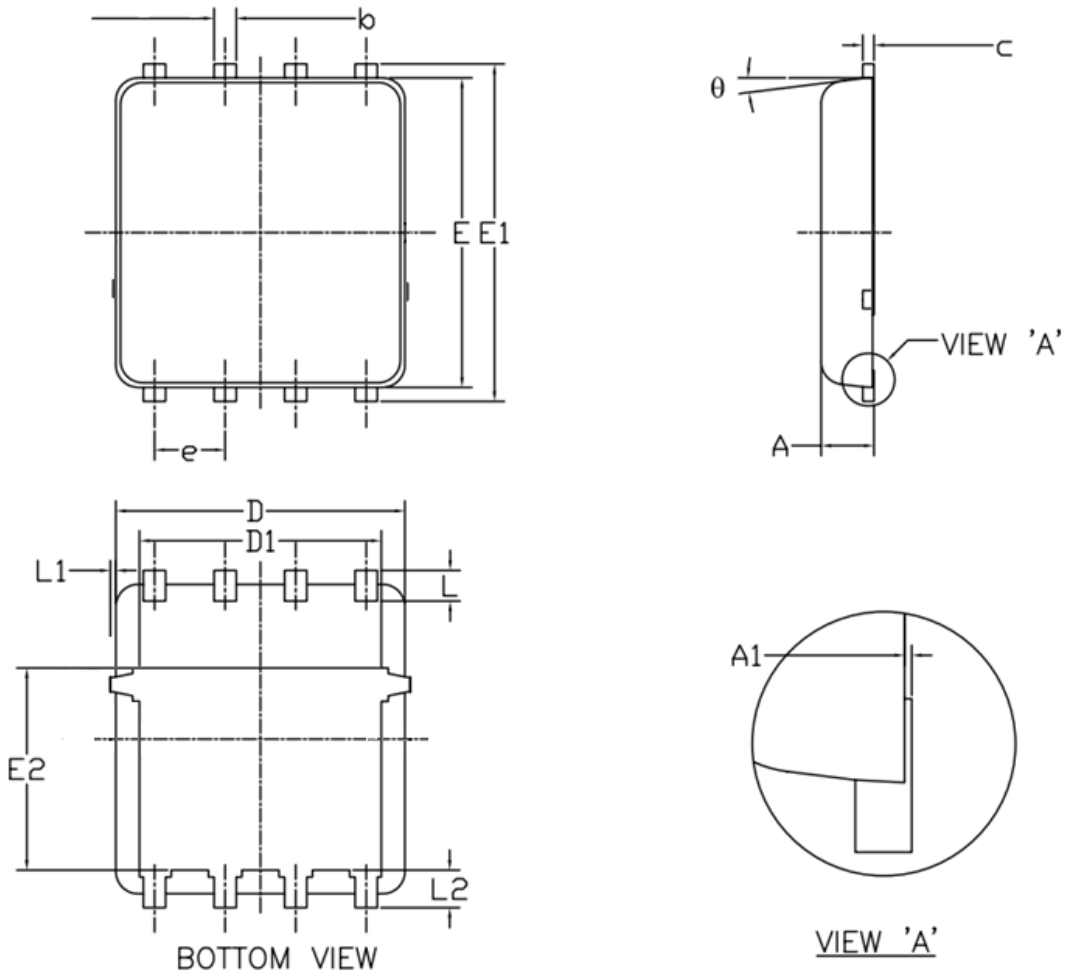
**Diagram11: Safe operating area**



**Diagram12: Typ. output characteristics**



**DFN5X6-8L Package Outline Dimensions**



Symbol	Dimensions (unit:mm)			Symbol	Dimensions (unit:mm)		
	Min	Typ	Max		Min	Typ	Max
<b>A</b>	0.90	1.00	1.20	<b>E1</b>	5.90	6.10	6.35
<b>A1</b>	0.00	--	0.05	<b>E2</b>	3.38	3.58	3.92
<b>b</b>	0.30	0.40	0.51	<b>e</b>	1.27 BSC		
<b>c</b>	0.20	0.25	0.33	<b>L</b>	0.51	0.61	0.71
<b>D</b>	4.80	4.90	5.40	<b>L1</b>	--	--	0.15
<b>D1</b>	3.61	4.00	4.25	<b>L2</b>	0.41	0.51	0.61
<b>E</b>	5.65	5.80	6.06	<b>theta</b>	0°	--	12°